## NSN 5961-01-418-3884

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-418-3884 **Inclosure Material:** Ceramic **Overall Length:** Between 0.168 inches and 0.230 inches **Overall Height:** Between 0.091 inches and 0.128 inches Overall Width: Between 0.091 inches and 0.128 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 working peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Terminals silver **Precious Material:** Silver **Test Data Document:** 13160-7575607 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: